

E(rasmus) Mundus on Innovative Microwave Electronics and Optics



Introduction to lasers

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Chapter 2: Amplifier gain











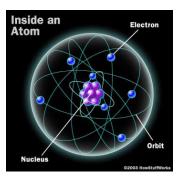




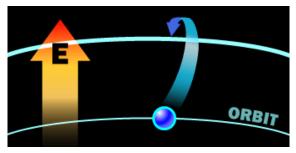
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I - Population inversion

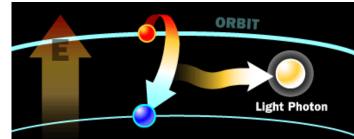
1. Generalities



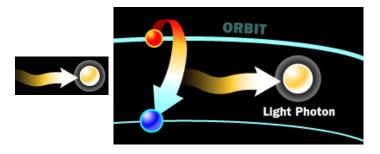
3 types of photon-atom interaction



Absorption



Spontaneous emission

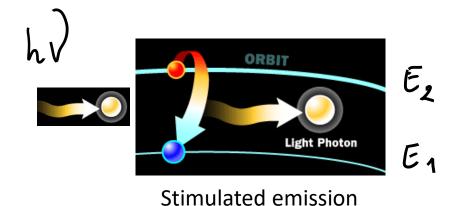


Stimulated emission





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The emitted photon has the same:

- frequency $\, {oldsymbol {\cal V}} \,$
- phase
- polarization
- direction of propagation

that the incident photon

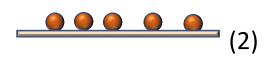
$$V = \frac{c}{\lambda}$$

Requirements:

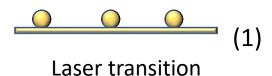
- E incident photon = E transition
- population inversion ΔN :

GAIN / AMPLIFICATION

Number of atoms/volume unit in the excited state > Number of atoms/volume unit in the fundamental state



$$\Delta N = N2 - N1 > 0$$





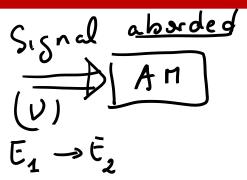
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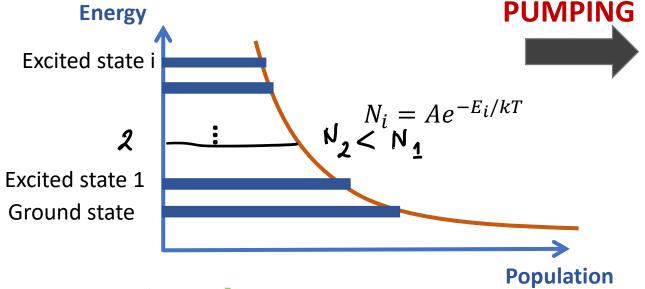
If $\Delta N > 0$: amplifying medium

If $\Delta N < 0$: absorbent medium

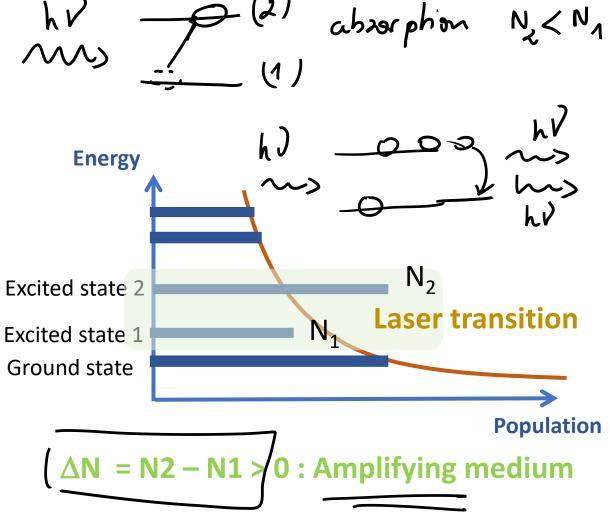
If $\Delta N = 0$: transparent medium



Steady state: populations governed by Boltzmann statistics







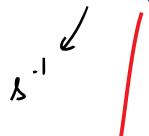




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□W = probability density (s⁻¹) that an unexcited atom absorb one single photon

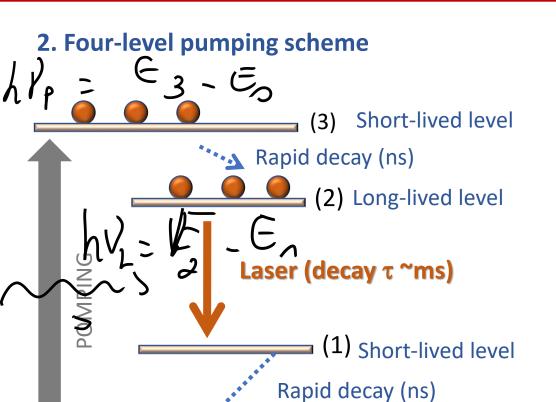
$$\square W = \sigma(v).\phi \longrightarrow cm^2. \Rightarrow 1$$



$$\sigma(v)$$
: transition cross section at the frequency v i.e. transition probability between two energy levels ϕ : photon-flux density (photons /cm².s) = I/h v and I(z) = $\frac{\varepsilon_0 c}{2}$. $|E(z)|^2$

W: probability density of both stimulated emission and absorption

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VP> VL => AP < AL for 3. Level pumping Syst Decouse (1) to hot the fundamental level used by

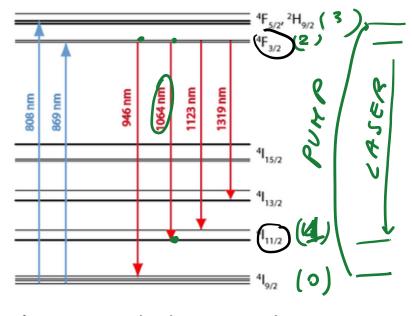
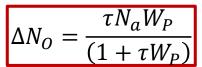


Figure 1: Energy level structure and common pump and laser transitions of the trivalent neodymium ion in Nd³⁺:YAG.

https://www.rp-photonics.com/yag_lasers.html

Narrow bandwidth: 120GHz, 0.4nm

→ without tunability



- Population inversion (without signal)
- Na = N_1+N_2 : Total number of atoms per volume unit
- W_P: pumping rate (s⁻¹), transition probability between levels (0) and (3)



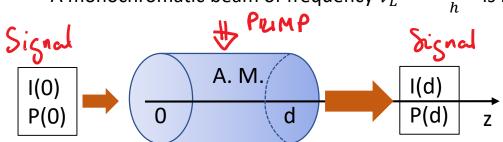
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II - Small-signal gain

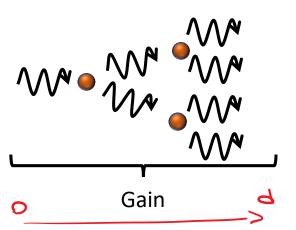
→ Link between gain and population inversion

Concept of gain

A monochromatic beam of frequency $v_L = \frac{E_2 - E_2}{h}$ is illuminating an amplifying medium under pumping and population inversion



$$G_0 = \frac{P(d)}{P(0)}$$



Note:
$$I = \frac{P}{A}$$
 (Wm⁻²)

of the beam in the A.M.

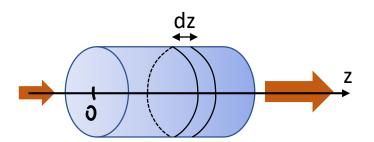
The intensity I(z) increases as the length of propagation inside the amplifying medium increases





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Let us consider an incremental cylinder of length dz and unit area



 $\phi(z)$: photon flux density **entering** the cylinder (m^2

 $\phi(z+dz) = \phi(z) + d\phi$: photon flux density **exiting** the cylinder

To complete
$$d\phi$$
 = number of phatons gained by unit time and unit volume $(W.\Delta N_0)$
 $m^{-2}s^{-1}$. length of propagation (dz)
 $m = s$
 $m =$

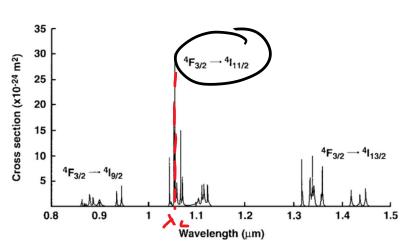
$$\frac{d\phi}{\phi} = 5\Delta N_0 dz$$

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Comment:

 γ_0 is a function of the frequency ν : $\gamma_0(\nu) = \Delta N_0 \sigma(\nu)$





Emission cross section of a Nd/YAG crystal

wavelength (nm) 1100

Figure 1: Effective absorption and emission cross sections of ytterbium-doped germanosilicate glass, as used in the cores of ytterbium-doped fibers. (Data from spectroscopic measurements by R. Paschotta)

https://www.rp-photonics.com/transition_cross_sections.html

at 980 nm -> pump absorption is more efficient than at 920 rm beret need to cool the pump Loser diode to ensure that the wavelengh does not shift out of the peak of the absorption Cross section.

In the following, for
the colculus of the
Gain,
$$V = V_L$$
 (fixed)

 $V = V_L = V_L$





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Gain of amplification:

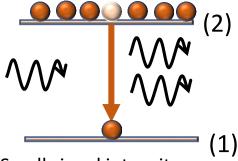
$$G_0 = \frac{P(d)}{P(0)} = e^{\gamma_0 d}$$
 with $\gamma_0 = \sigma$. ΔN_0

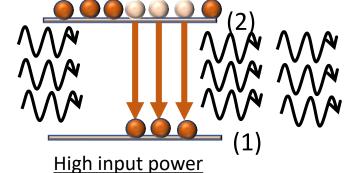


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III - Gain saturation

$$\Delta N(P) = \frac{\Delta N_0}{1 + P/P_{sat}}$$
 P: signal power Psat: saturation power





Small signal intensity Unmodified population inversion

Reduced population inversion

To complete